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New Possibilities to Facilitate Collimation of Both Positively and Negatively Charged Particle Beams by Crystals

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Outline

Introduction

Channeling probability increase at high energies by the *crystal cut*

Multiple *volume reflection by crystal axes* in a single crystal

Conclusions

The LHC upgrade need

Fifteen years of planning and R&D, followed by over 10 years of construction, should be followed by a comparable period of the LHC exploitation.

Luminosity upgrade:
$$L = 10^{34} cm^{-2} s^{-1} \times 10^{10}$$

Energy upgrade: $\varepsilon = 7TeV \times 2$

What is better?

Luminosity upgrade in more efficient at M < 3.5 TeV



Integrated luminosity required to produce 100 W' events in pp collisions at $\sqrt{S} = 14$ and 28 TeV.

Statistics is too low for a clear separation among possible models at integrated luminosity of 100fb⁻¹



Average leptonic forward-backward asymmetry, as a function of the dimuon invariant mass, for various Z' models.

Thus, the luminosity upgrade have to be very efficient

$L = 10^{34} cm^{-2} s^{-1} \times 10$

However luminosity increase will intensify the beam halo formation



Crystals improve collimation efficiency



At least 15% of particles **dechannel** due to incoherent scattering



The capture probability can be increased bya plane cutV.V.Tikhomirov, JINST, 2(2007)P08006



Transverse energy reduction by the cut - 1



The cut diminishes the potential energy V(x) conserving the transverse kinetic energy

Particle motion in the cut region $0 < z < z_2$



$$V(x) = \frac{k}{2} \left(x - \frac{d}{2} \right)^2, \quad z = \upsilon_{\parallel} \cdot t, \quad \omega = \sqrt{\frac{k}{\epsilon}}.$$



$$z = 0$$

$$x_0 \equiv x(0) = d/2 + a_0$$

$$\upsilon_0 \equiv \upsilon_x(0)$$

$$\varepsilon_{\perp 0} = \varepsilon \frac{\upsilon_0^2}{2} + V(x_0) = \varepsilon \frac{\upsilon_0^2}{2} + k \frac{a_0^2}{2}$$

$$z = z_1$$

$$x_1 \equiv x(t_1) = d/2 + a_0 \cdot \cos(\omega t_1) + \upsilon_0 \cdot \sin(\omega t_1)$$

$$\upsilon_1 \equiv \upsilon_x(t_1) = -a_0 \omega \cdot \sin(\omega t_1) + \upsilon_0 \omega \cdot \cos(\omega t_1)$$

$$\varepsilon_{\perp_1} = \varepsilon \frac{\upsilon_1^2}{2} + V(x_1) \Longrightarrow \varepsilon \frac{\upsilon_1^2}{2} + 0$$

$$z = z_2$$

$$x_2 \equiv x(t_2) = x_1 + \upsilon_1 \cdot (t_2 - t_1)$$

$$\upsilon_2 \equiv \upsilon_x(t_2) = \upsilon_1$$

$$\varepsilon_{\perp 2} = \varepsilon \frac{\upsilon_1^2}{2} + V(x_2) \le \frac{1}{2} \varepsilon_{\perp 0}$$

To the optimization of the cut coordinates $z_{1,2}$



d2.0 _{x, Å}

X_{2 1.5}

1.0

 $V(x_2)$

0 X₀X

0.5

$$\begin{split} \varepsilon_{\perp_{2}} &= \varepsilon \frac{\upsilon_{1}^{2}}{2} + V(x_{2}) \equiv A\upsilon_{0}^{2} + B\upsilon_{0}a_{0} + Ca_{0}^{2} \\ &= \frac{\varepsilon}{2} \left\{ 1 + \omega(t_{2} - t_{1}) \left[2\cos(\omega t_{1})\sin(\omega t_{1}) + \omega(t_{2} - t_{1})\cos^{2}(\omega t_{1}) \right] \right\} \upsilon_{0}^{2} \\ &+ \sqrt{k\varepsilon} \cdot \omega(t_{2} - t_{1}) \left\{ \left[\cos^{2}(\omega t_{1}) - \sin^{2}(\omega t_{1}) \right] - \omega(t_{2} - t_{1})\cos(\omega t_{1})\sin(\omega t_{1}) \right\} \upsilon_{0}a_{0} \\ &+ \frac{k}{2} \left\{ 1 - \omega(t_{2} - t_{1}) \left[2\cos(\omega t_{1})\sin(\omega t_{1}) - \omega(t_{2} - t_{1})\sin^{2}(\omega t_{1}) \right] \right\} a_{0}^{2} \\ B = 0 \implies \\ z_{2} = z_{1} + 2 \cdot ctg(2\omega t_{1})\upsilon_{\parallel} / \omega \\ \varepsilon_{\perp_{2}} = \varepsilon \frac{\upsilon_{0}^{2}}{2}ctg^{2}(\omega t_{1}) + k \frac{a_{0}^{2}}{2}tg^{2}(\omega t_{1}) \implies \frac{a}{y} + b \cdot y \implies \\ z_{1} = \frac{\upsilon_{\parallel}}{\omega} \arctan \sqrt{\frac{\vartheta_{0}}{\theta(a_{0})}}, \quad \theta(a_{0}) \equiv \frac{\sqrt{2V(a_{0})/\varepsilon}}{\upsilon_{\parallel} / c}, \quad V(a_{0}) = \frac{1}{2}ka_{0}^{2}. \\ \left(\varepsilon_{\perp_{2}} \right)_{min} = 2 \frac{\vartheta_{0}}{\theta(a_{0})} V(a_{0}) \implies \vartheta_{0} < \frac{1}{4}\sqrt{2V(a_{0})/\varepsilon} \\ z_{2} / z_{1} = 4.235 \quad at \quad \vartheta_{0} = 0.25\sqrt{2V(a_{0})/\varepsilon} \end{split}$$

Phase space transformation by the cut



Protons are removed from the high nuclear density regions

Transverse energy reduction by the cut - 2



Only 1-2% of protons avoid transverse energy reduction by the cut

Dechanneling suppression by the cut at 7 TeV



The cut decreases the dechanneling probability from 18 to 1-2%

Dechanneling suppression by the cut at 400 GeV



The cut decreases the dechanneling probability from 15 to 1%





$$y(s) \approx y_0 \left[1 + \frac{\beta'(s - s_0)}{2\beta} - \frac{(s - s_0)^2}{2\beta^2} \right] = y_{\max} - \frac{y_0}{2\beta^2} \left(s - s_0 - \frac{1}{2}\beta'\beta \right)^2,$$

$$y_{\max} = y_0 \left(1 + \frac{1}{8}\beta'^2 \right) = y_{cr} + \Delta, \quad y_0 \approx a\sqrt{\beta(s_0)} \approx k\sigma = k\sqrt{\epsilon\beta}, \quad \epsilon - \text{emittance}, \quad k \approx 6$$

$$y(s) > y_{cr} \quad \text{if} \quad \frac{y_0}{2\beta^2} \left(s - s_0 - \frac{1}{2}\beta'\beta \right)^2 < \Delta, \quad \text{or} \quad \left| s - s_0 - \frac{1}{2}\beta'\beta \right| < \sqrt{\frac{2\Delta}{y_0}}\beta << \beta$$

$$\begin{split} \delta\vartheta &= y'(s) = -\frac{y_0}{\beta^2} \left(s - s_0 - \frac{1}{2} \beta' \beta \right), \\ \left| \delta\vartheta \right| &\leq \delta\vartheta_{\max} \approx \frac{\sqrt{2y_0 \Delta}}{\beta} \approx 0.2 \mu rad, \quad \sqrt{\langle \delta\vartheta^2 \rangle} \approx 0.1 \mu rad, \\ \text{for } \Delta &= 1 \mu m, \quad \beta = 350 m, \quad y_{cr} = 2.5 \, mm \end{split}$$

A pair of crystals with cuts bent in orthogonal planes allows to deflect 99.9% of protons



SIMOX technology BOX layer can be used instead of *very thin* cut



High resolution image of SIMOX wafer





BOX layer "focuses" protons like a cut diminishing their transverse energy

$$z_1 = 20 nm,$$

$$z_2 = 80 nm,$$

$$z_3 = 1 \mu m,$$

$$E_p = 7 MeV$$

See the poster: V. Guidi, A. Mazzolari, and V.V. Tikhomirov Increase of Probability of Particle Capture into the Channeling Regime by the Buried Oxide Layer The cut allows to increase the proton (nuclei) deflection efficiency and to decrease the accompanying proton absorption by 1-2 orders of magnitude

Volume Reflection prediction

A.M.Taratin and S.A.Vorobiev, Phys. Lett. A119 (1987) 425

and

A.M.Taratin and S.A.Vorobiev, NIM B26 (1987) 512





Volume reflection CERN H8-RD22 experiment Sept 2006



Volume reflection by crystal axes V.V. Tikhomirov, PLB 655(2007)217





Axes form *many* inclined reflecting planes

Protons are reflected from *many* crystal plane sets of *one* crystal



Reflection from many crystal planes increase VR angle **4** *times* – **1** (LHC case)



$$\upsilon_{x}(x) = \sqrt{\frac{2}{\varepsilon}} \left(\varepsilon_{\perp x} - V(x) + \frac{p\upsilon_{\parallel}}{R} x \cdot sin\alpha \right) \cdot c$$

$$\varepsilon_{\perp x} - V(x_{turn}) + \frac{p\upsilon_{\parallel}}{R} x_{turn} \cdot sin\alpha = 0$$

$$\widetilde{\upsilon}_{x} = \sqrt{\frac{2}{\varepsilon}} \left(\varepsilon_{\perp x} - V(x_{turn}) + \frac{p\upsilon_{\parallel}}{R} x_{turn} \cdot sin\alpha \right) \cdot c$$

$$\upsilon_{y}(x) = \sqrt{\frac{2}{\varepsilon}} \left(\varepsilon_{\perp x} - \frac{p\upsilon_{\parallel}}{R} y \cdot cos\alpha \right) \cdot c$$

$$\theta_{x} = \theta_{R}(R/sin\alpha) \cdot sin\alpha$$

$$\theta_{y} = \theta_{R}(R/sin\alpha) \cdot cos\alpha$$

$$\theta_{R}(R/sin\alpha) = \frac{2\upsilon_{\parallel}}{R/sin\alpha} \int_{x_{turn}}^{\infty} \left(\frac{1}{\widetilde{\upsilon}_{x}} - \frac{1}{\upsilon_{x}(x)} \right) dx$$

V.V. Tikhomirov, PLB 655(2007)217

The approach of V.A. Maisheev, Phys. Rev. ST Accel. Beams 10:084701,2007 was used.

Direct simulations of distribution of multiple reflected protons (LHC case)



Reflection from many crystal planes increase VR angle **4** times – **2** (LHC case)



Reflection from many planes in single **W** crystal allows to reach a big one-pass deflection efficiency



To the observations at the SPS



Volume reflection of *negative* particles



Planar channeling of negative particles in bent crystals

ε = 120 GeV, 0.2 mm, 170cm

- - $\delta\theta$ = 5 µrad 23.0%

••• $\delta \theta = 10 \, \mu rad, \, 14.4\%$

100

26.5%

150

 $\delta \theta = 0$

50

 $\theta_{r}, \mu rad$



Reflection from different crystal planes allows to increase the volume reflection angle about 4 times

General Conclusion:

New technical means for the LHC luminosity upgrade are suggested **Experimental investigation** has started

Thank you for attention!